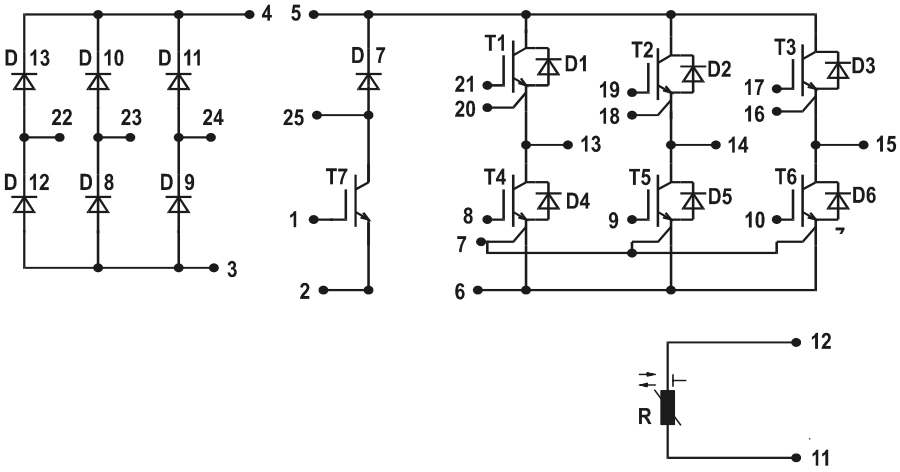
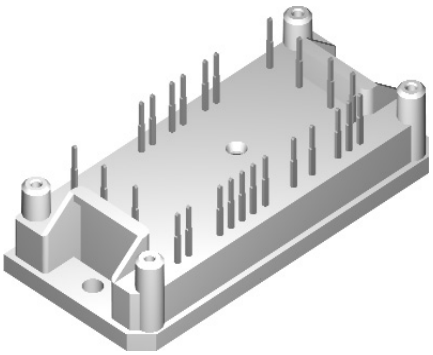
Converter - Brake - Inverter Module (CBI1)

NPT IGBT





Three Phase Rectifier	Brake Chopper	Three Phase Inverter
V_{RRM} = 1600V	V_{CES} = 1200 V	V_{CES} = 1200 V
I_{DAVM25} = 130 A	I_{C25} = 19 A	I_{C25} = 30 A
I_{FSM} = 320 A	$V_{CE(sat)}$ = 2.9 V	$V_{CE(sat)}$ = 3 V

Input Rectifier Bridge D8 - D13

Symbol	Conditions	Maximum Ratings	
V_{RRM}		1600	V
I_{FAV}	T_C = 80°C; sine 180°	31	A
I_{DAVM}	bridge output current; T_C = 80°C; rectangular; d = 1/3	89	A
I_{FSM}	T_{VJ} = 25°C; t = 10 ms; sine 50 Hz	320	A
P_{tot}	T_C = 25°C	80	W

Symbol	Conditions	Characteristic Values (T_{VJ} = 25°C, unless otherwise specified) min.	typ.	max.	
V_F	I_F = 30 A; T_{VJ} = 25°C		1.0	1.35	V
	T_{VJ} = 125°C		1.1		V
I_R	$V_R = V_{RRM}$; T_{VJ} = 25°C			0.02	mA
	T_{VJ} = 125°C		0.4		mA
R_{thJC}	(per diode)			1.4	K/W
R_{thCH}			0.45		K/W

Application: AC motor drives with

- Input from single or three phase grid
- Three phase synchronous or
- asynchronous motor
- electric braking operation

Features

- High level of integration - only one power semiconductor module required for the whole drive
- Inverter with NPT IGBTs
  - low saturation voltage
  - positive temperature coefficient
  - fast switching
  - short tail current
- Epitaxial free wheeling diodes with Hiperfast and soft reverse recovery
- Industry standard package with insulated copper base plate and soldering pins for PCB mounting
- Temperature sense included

IXYS reserves the right to change limits, test conditions and dimensions.

425

Output Inverter T1 - T6

Symbol	Conditions	Maximum Ratings	
V_{CES}	T_{VJ} = 25°C to 150°C	1200	V
V_{GES}	Continuous	± 20	V
V_{GEM}	Transient	± 30	V
I_{C25}	T_C = 25°C	30	A
I_{C80}	T_C = 80°C	21	A
RBSOA	V_{GE} = ±15 V; R_G = 82 Ω; T_{VJ} = 125°C Clamped inductive load; L = 100 µH	I_{CM} = 60 $V_{CEK} \le V_{CES}$	A
t_{SC} (SCSOA)	V_{CE} = 1200 V; V_{GE} = ±15 V; R_G = 82 Ω; T_{VJ} = 125°C non-repetitive	10	µs
P_{tot}	T_C = 25°C	130	W

Symbol	Conditions	Characteristic Values (T_{VJ} = 25°C, unless otherwise specified) min.	typ.	max.	
$V_{CE(sat)}$	I_C = 30 A; V_{GE} = 15 V; T_{VJ} = 25°C		3.0	3.8	V
	T_{VJ} = 125°C		3.4		V
$V_{GE(th)}$	I_C = 0.6 mA; V_{GE} = V_{CE}	4.5		6.5	V
I_{CES}	V_{CE} = V_{CES}; V_{GE} = 0 V; T_{VJ} = 25°C			1	mA
	T_{VJ} = 125°C		1.5		mA
I_{GES}	V_{CE} = 0 V; V_{GE} = ± 20 V			200	nA
$t_{d(on)}$	Inductive load, T_{VJ} = 125°C V_{CE} = 600 V; I_C = 15 A V_{GE} = ±15 V; R_G = 82 Ω		100		ns
t_r			80		ns
$t_{d(off)}$			500		ns
t_f			70		ns
E_{on}			2.3		mJ
E_{off}			1.8		mJ
C_{ies}	V_{CE} = 25 V; V_{GE} = 0 V; f = 1 MHz		1000		pF
Q_{Gon}	V_{CE} = 600V; V_{GE} = 15 V; I_C = 17.5 A		70		nC
R_{thJC}	(per IGBT)			0.95	K/W
R_{thCH}			0.35		K/W

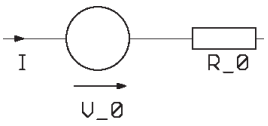
Output Inverter D1 - D6

Symbol	Conditions	Maximum Ratings	
I_{F25}	T_C = 25°C	49	A
I_{F80}	T_C = 80°C	32	A

Symbol	Conditions	Characteristic Values min.	typ.	max.	
V_F	I_F = 30 A; V_{GE} = 0 V; T_{VJ} = 25°C			2.9	V
	T_{VJ} = 125°C		2.0		V
I_{RM}	I_F = 30 A; di_F/dt = -500A/µs; T_{VJ} = 125°C		27		A
t_{rr}	V_R = 600 V; V_{GE} = 0 V		150		ns
R_{thJC}	(per diode)			0.9	K/W
R_{thCH}			0.3		K/W

Equivalent Circuits for Simulation

Conduction



D8 - D13

Rectifier Diode (typ. at T_J = 125°C)
V_0 = 0.90V; R_0 = 9 mΩ

T1 - T6 / D1 - D6

IGBT (typ. at V_{GE} = 15 V; T_J = 125°C)
V_0 = tbd V; R_0 = tbd mΩ

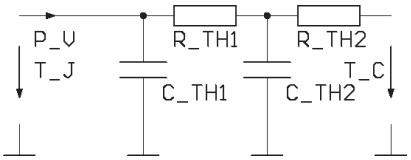
Free Wheeling Diode (typ. at T_J = 125°C)
V_0 = 1.5 V; R_0 = 14 mΩ

T7 / D7

IGBT (typ. at V_{GE} = 15 V; T_J = 125°C)
V_0 = 1.50 V; R_0 = 120 mΩ

Free Wheeling Diode (typ. at T_J = 125°C)
V_0 = 1.46 V; R_0 = 63 mΩ

Thermal Response



D8 - D13

Rectifier Diode (typ.)
C_{th1} = tbd J/K; R_{th1} = tbd K/W
C_{th2} = tbd J/K; R_{th2} = tbd K/W

T1 - T6 / D1 - D6

IGBT (typ.)
C_{th1} = tbd J/K; R_{th1} = tbd K/W
C_{th2} = tbd J/K; R_{th2} = tbd K/W

Free Wheeling Diode (typ.)
C_{th1} = tbd J/K; R_{th1} = tbd K/W
C_{th2} = tbd J/K; R_{th2} = tbd K/W

T7 / D7

IGBT (typ.)
C_{th1} = tbd J/K; R_{th1} = tbd K/W
C_{th2} = tbd J/K; R_{th2} = tbd K/W

Free Wheeling Diode (typ.)
C_{th1} = tbd J/K; R_{th1} = tbd K/W
C_{th2} = tbd J/K; R_{th2} = tbd K/W

425

Brake Chopper T7

Symbol	Conditions	Maximum Ratings	
V_{CES}	T_{VJ} = 25°C to 150°C	1200	V
V_{GES}	Continuous	± 20	V
V_{GEM}	Transient	± 30	V
I_{C25}	T_C = 25°C	19	A
I_{C80}	T_C = 80°C	13	A
RBSOA	V_{GE} = ±15 V; R_G = 82 Ω; T_{VJ} = 125°C Clamped inductive load; L = 100 µH	I_{CM} = 20 $V_{CEK} \le V_{CES}$	A
t_{SC} (SCSOA)	V_{CE} = 720 V; V_{GE} = ±15 V; R_G = 82 Ω; T_{VJ} = 125°C non-repetitive	10	µs
P_{tot}	T_C = 25°C	90	W

Symbol	Conditions	Characteristic Values			
(T_{VJ} = 25°C, unless otherwise specified)		min.	typ.	max.	
$V_{CE(sat)}$	I_C = 15 A; V_{GE} = 15 V; T_{VJ} = 25°C		2.9	3.4	V
	T_{VJ} = 125°C		3.5		V
$V_{GE(th)}$	I_C = 0.4 mA; V_{GE} = V_{CE}	4.5		6.5	V
I_{CES}	V_{CE} = V_{CES}; V_{GE} = 0 V; T_{VJ} = 25°C			0.5	mA
	T_{VJ} = 125°C		0.8		mA
I_{GES}	V_{CE} = 0 V; V_{GE} = ± 20 V			100	nA
$t_{d(on)}$	Inductive load, T_{VJ} = 125°C V_{CE} = 600 V; I_C = 10 A V_{GE} = ±15 V; R_G = 82 Ω		45		ns
t_r			40		ns
$t_{d(off)}$			290		ns
t_f			60		ns
E_{on}			1.2		mJ
E_{off}			1.1		mJ
C_{ies}	V_{CE} = 25 V; V_{GE} = 0 V; f = 1 MH z		600		pF
Q_{Gon}	V_{CE} = 600 V; V_{GE} = 15 V; I_C = 10 A		45		nC
R_{thJC}				1.37	K/W
R_{thCH}			0.45		K/W

Brake Chopper D7

Symbol	Conditions	Maximum Ratings	
V_{RRM}	T_{VJ} = 25°C to 150°C	1200	V
I_{F25}	T_C = 25°C	15	A
I_{F80}	T_C = 80°C	10	A

Symbol	Conditions	Characteristic Values			
		min.	typ.	max.	
V_F	I_F = 15 A; T_{VJ} = 25°C			3.5	V
	T_{VJ} = 125°C		2.0		V
I_R	V_R = V_{RRM}; T_{VJ} = 25°C			0.06	mA
	T_{VJ} = 125°C		0.2		mA
I_{RM}	I_F = 10 A; di_F/dt = -400 A/µs; T_{VJ} = 125°C		13		A
t_{rr}	V_R = 600 V		110		ns
R_{thJC}				2.5	K/W
R_{thCH}			0.85		K/W

425

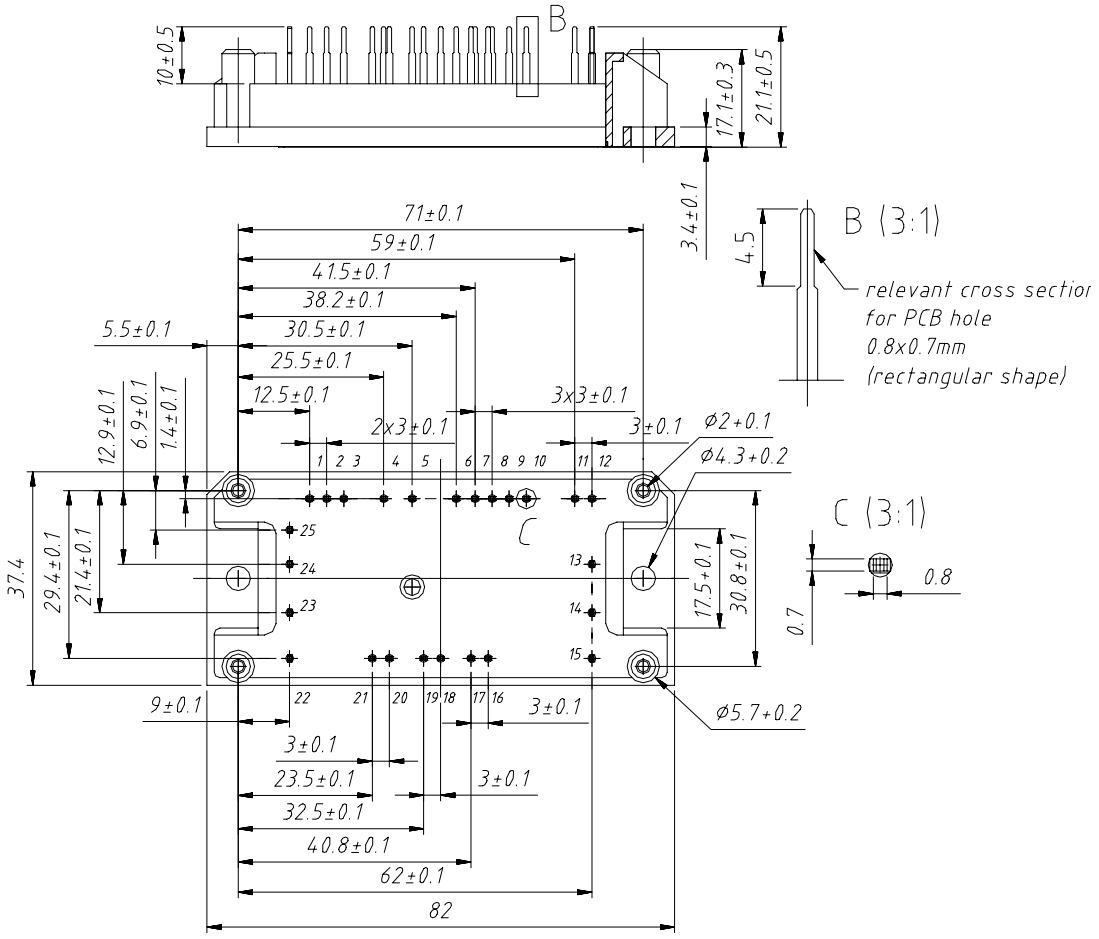
Temperature Sensor NTC

Symbol	Conditions	Characteristic Values min.	typ.	max.	
R_{25}	T = 25°C	4.45	4.7	5.0	kΩ
$B_{25/85}$			3510		K

Module

Symbol	Conditions	Maximum Ratings	
T_{VJ}	Operating	-40...+125	°C
T_{JM}		150	°C
T_{stg}		-40...+125	°C
V_{ISOL}	$I_{ISOL} \leq 1$ mA; 50/60 Hz	2500	V~
M_d	Mounting torque (M4)	2.0 - 2.2	Nm

Symbol	Conditions	Characteristic Values min.	typ.	max.	
d_S	Creepage distance (towards heatsink)	12.7			mm
d_A	Strike distance in air (towards heatsink)	12.7			mm
Weight			40		g



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